NSN 5961-01-097-2667

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-097-2667 **Inclosure Material:** Glass **Overall Length:** 2.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.104 inches **End Application:** Lgm 30 minuteman **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 8.820 breakdown voltage, dc **Current Rating Per Characteristic:** 100.00 nanoamperes reverse current, dc **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0